

MDL-XN-3900/1-300mW

SPECIFICATIONS

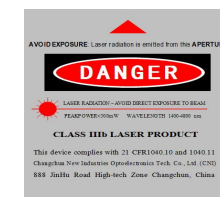


INFRARED QCL DIODE
LASER AT 3900nm

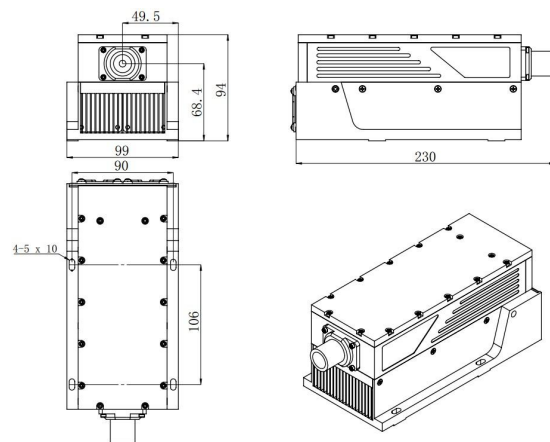
It features ultra compact design, long lifetime, cost-effectiveness and easy operation. They are widely used in measurement, communication, spectrum analysis, etc.



Central wavelength (μm)	3.9±0.3
Operating mode	CW
Output power (mW) ¹	1-300
Power stability (rms, 4 hours ± 3°C)	<3%, <2%, <1%
Transverse mode	Near TEM ₀₀
Beam diameter at the aperture (mm)	<3.0
Beam divergence, full angle (mrad)	<5.0
Warm-up time (minutes)	<10
Cooled method	Air cooled
Beam height from base plate (mm)	68.4
Operating temperature (°C)	10-35
Power supply (100-240VAC)	PSU-H-LED
Modulation option	DC-1kHz; TTL and Analog optional
Expected lifetime (hours)	>10000

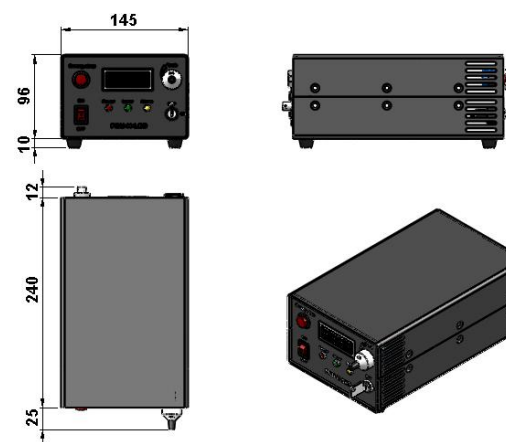


LASER HEAD



230 (L) × 99 (W) × 94 (H) mm³, 3.0kg

POWER SUPPLY²



277 (L) × 145 (W) × 106 (H) mm³, 2.3kg

1 Any power level can be selected in this range.

2 Output power adjustable 10-100%; RS232 control optional.

Website: <http://www.cnilaser.com> E-mail: sales@cnilaser.com Tel: +86-431-85603799 Fax: +86-431-89216068